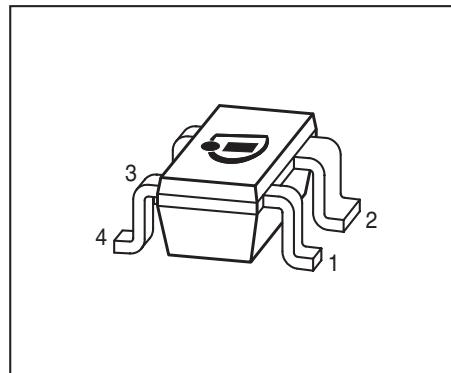


## Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain broadband amplifiers at collector currents from 1 mA to 20 mA
- $f_T = 8$  GHz,  $NF_{min} = 0.9$  dB at 900 MHz
- Pb-free (RoHS compliant) package
- Qualification report according to AEC-Q101 available



**ESD (Electrostatic discharge)** sensitive device, observe handling precaution!

Type	Marking	Pin Configuration						Package
BFP182R	RGs	1=E	2=C	3=E	4 = B	-	-	SOT143R

**Maximum Ratings** at  $T_A = 25$  °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	12	V
Collector-emitter voltage	$V_{CES}$	20	
Collector-base voltage	$V_{CBO}$	20	
Emitter-base voltage	$V_{EBO}$	2	
Collector current	$I_C$	35	mA
Base current	$I_B$	4	
Total power dissipation <sup>1)</sup>	$P_{tot}$	250	mW
$T_S \leq 69$ °C			°C
Junction temperature	$T_J$	150	
Storage temperature	$T_{Stg}$	-55 ... 150	

### Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	$R_{thJS}$	325	K/W

<sup>1</sup> $T_S$  is measured on the collector lead at the soldering point to the pcb

<sup>2</sup>For the definition of  $R_{thJS}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

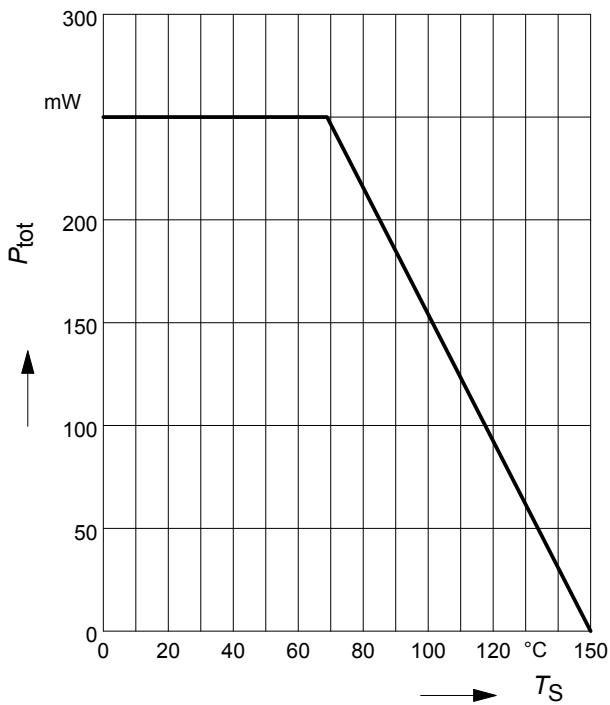
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Collector-emitter breakdown voltage $I_C = 1 \text{ mA}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$	12	-	-	V
Collector-emitter cutoff current $V_{CE} = 20 \text{ V}, V_{BE} = 0$	$I_{CES}$	-	-	100	$\mu\text{A}$
Collector-base cutoff current $V_{CB} = 10 \text{ V}, I_E = 0$	$I_{CBO}$	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 1 \text{ V}, I_C = 0$	$I_{EBO}$	-	-	1	$\mu\text{A}$
DC current gain $I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}$ , pulse measured	$h_{FE}$	70	100	140	-

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

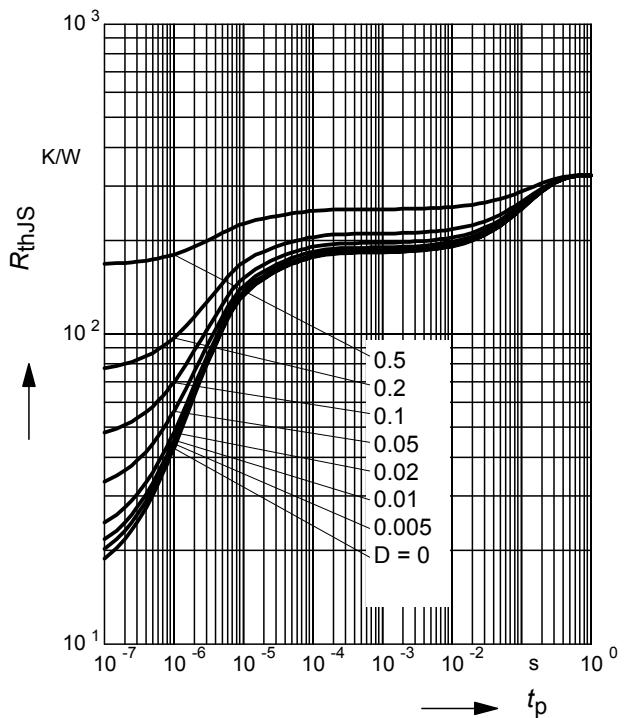
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>AC Characteristics</b> (verified by random sampling)					
Transition frequency $I_C = 15 \text{ mA}, V_{CE} = 8 \text{ V}, f = 500 \text{ MHz}$	$f_T$	6	8	-	GHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0 \text{ V}$ , emitter grounded	$C_{cb}$	-	0.25	0.4	pF
Collector emitter capacitance $V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0 \text{ V}$ , base grounded	$C_{ce}$	-	0.3	-	
Emitter-base capacitance $V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{CB} = 0 \text{ V}$ , collector grounded	$C_{eb}$	-	0.8	-	
Minimum noise figure $I_C = 3 \text{ mA}, V_{CE} = 6 \text{ V}, Z_S = Z_{\text{Sopt}}$ , $f = 900 \text{ MHz}$ $I_C = 3 \text{ mA}, V_{CE} = 6 \text{ V}, Z_S = Z_{\text{Sopt}}$ , $f = 1.8 \text{ GHz}$	$NF_{\min}$	-	0.9	-	dB
-	-	-	1.3	-	
Power gain, maximum stable <sup>1)</sup> $I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_{\text{Sopt}}, Z_L = Z_{\text{Lopt}}$ , $f = 900 \text{ MHz}$	$G_{ms}$	-	22	-	dB
Power gain, maximum available <sup>2)</sup> $I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_{\text{Sopt}}, Z_L = Z_{\text{Lopt}}$ , $f = 1.8 \text{ GHz}$	$G_{ma}$	-	16.5	-	dB
Transducer gain $I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_L = 50 \Omega$ , $f = 900 \text{ MHz}$ $I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_L = 50 \Omega$ , $f = 1.8 \text{ GHz}$	$ S_{21e} ^2$	-	18	-	dB
-	-	-	12	-	

<sup>1</sup> $G_{ms} = |S_{21} / S_{12}|$ 
<sup>2</sup> $G_{ma} = |S_{21e} / S_{12e}| (k - (k^2 - 1)^{1/2})$

**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

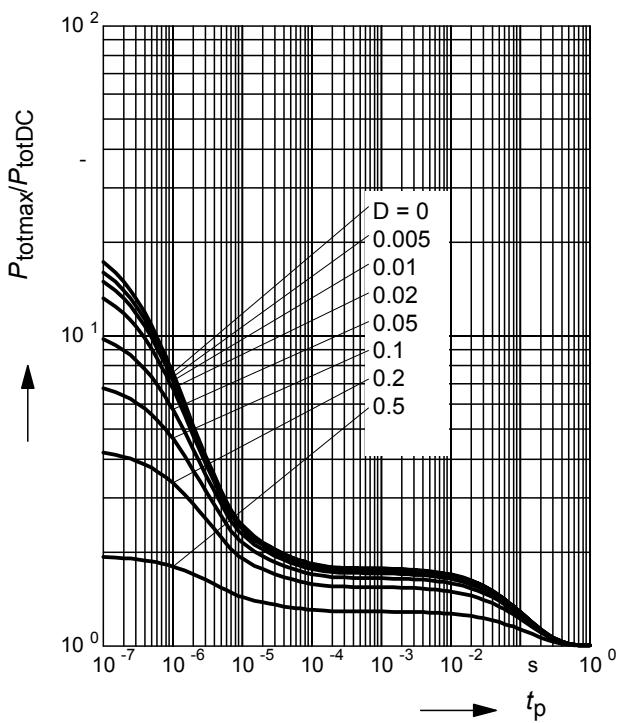


**Permissible Pulse Load  $R_{\text{thJS}} = f(t_p)$**

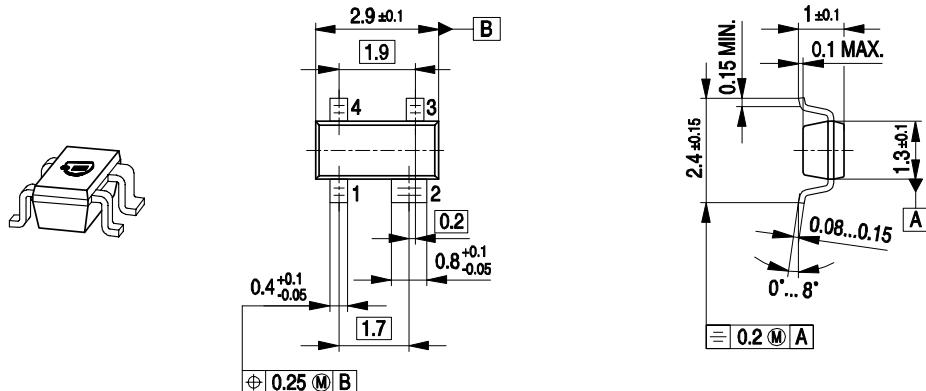


### Permissible Pulse Load

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$



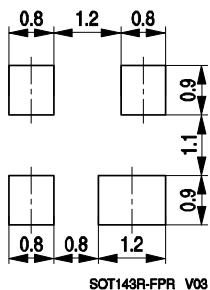
### Package Outline



Note: Mold flash, protrusions or gate burrs of 0,2 mm max. per side are not included

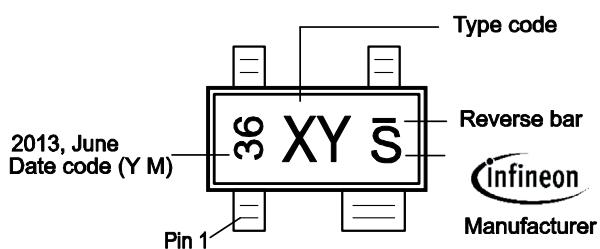
SOT143R-PO V03

### Foot Print



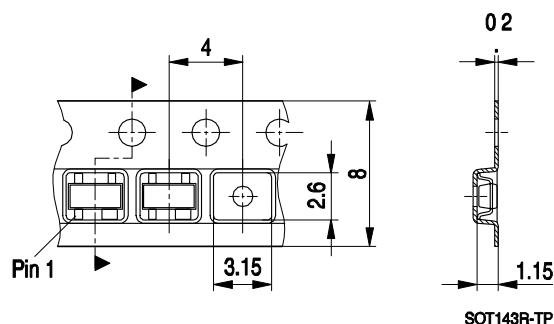
SOT143R-FPR V03

### Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel



SOT143R-TP

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